**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Very fast switching
- ElectroStatic Discharge (ESD) protection > 2 kV HBM
- Ultra thin package profile of 0.37 mm

## 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V
$V_{GS}$	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	-1	Α
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; $I_{D}$ = -1 A; $T_{j}$ = 25 °C		-	430	510	mΩ

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1 🔲	D I
2	S	source	2 3	
3	D	drain	Transparent top view  DFN1006B-3 (SOT883B)	G S 017aaa259

# 6. Ordering information

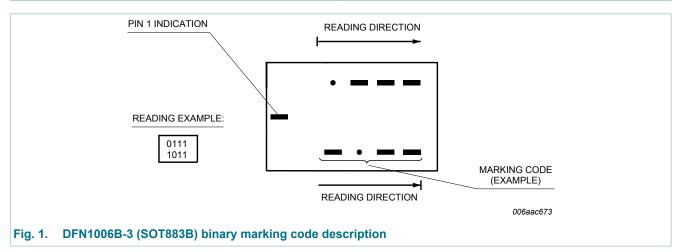
Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMZB320UPE	DFN1006B-3	DFN1006B-3: leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B		

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PMZB320UPE	0101 0010



## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit	
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V	
$V_{GS}$	gate-source voltage			-8	8	V	
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-1	Α	
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-0.6	Α	
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$		-	-4	Α	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	350	mW	
			[1]	-	760	mW	
		T <sub>sp</sub> = 25 °C		-	6250	mW	
T <sub>j</sub>	junction temperature			-55	150	°C	
T <sub>amb</sub>	ambient temperature			-55	150	°C	
T <sub>stg</sub>	storage temperature			-65	150	°C	
Source-drain diode							
Is	source current	T <sub>amb</sub> = 25 °C	[1]	-	-0.7	Α	

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

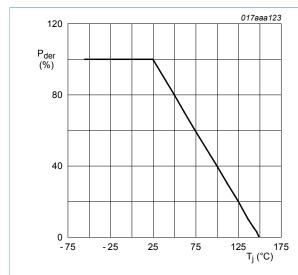


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

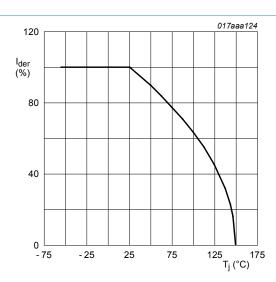


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

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Nexperia PMZB320UPE

#### 30 V, P-channel Trench MOSFET

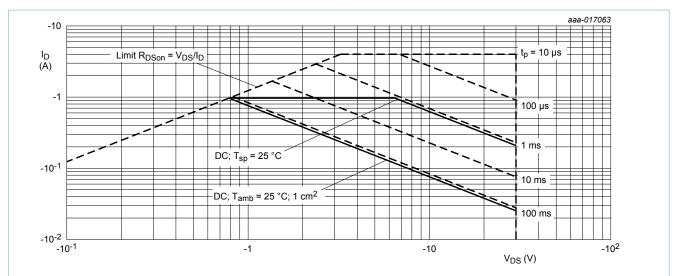


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uily a)	thermal resistance		[1]	-	315	360	K/W
	from junction to ambient		[2]	-	145	165	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	17	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

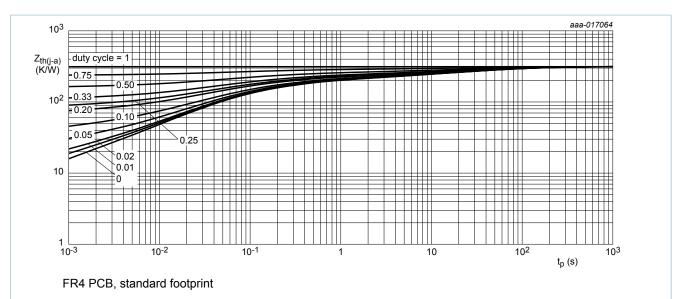


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

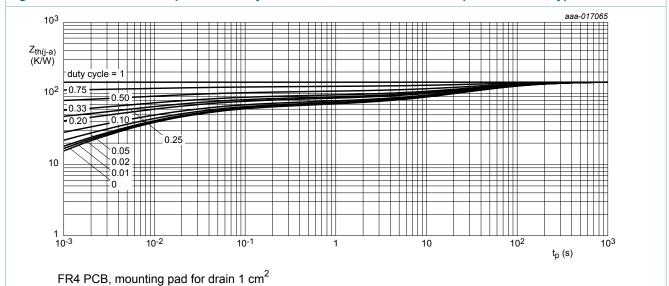


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		'			
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 $\mu$ A; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D$ = -250 $\mu$ A; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.45	-0.7	-0.95	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	5	μΑ
		V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-5	μA
		V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μΑ
		V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		V <sub>GS</sub> = 2.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
		V <sub>GS</sub> = -2.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -1 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	430	510	mΩ
re		V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -1 A; T <sub>j</sub> = 150 °C	-	680	810	mΩ
		V <sub>GS</sub> = -2.5 V; I <sub>D</sub> = -0.8 A; T <sub>j</sub> = 25 °C	-	570	770	mΩ
		V <sub>GS</sub> = -1.8 V; I <sub>D</sub> = -0.25 A; T <sub>j</sub> = 25 °C	-	750	1140	mΩ
		V <sub>GS</sub> = -1.5 V; I <sub>D</sub> = -0.01 A; T <sub>j</sub> = 25 °C	-	950	1610	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; $I_{D}$ = -1 A; $T_{j}$ = 25 °C	-	2.1	-	S
Dynamic ch	naracteristics		'			,
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -15 V; $I_{D}$ = -1 A; $V_{GS}$ = -4.5 V;	-	1.4	-	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C	-	0.2	-	nC
$Q_{GD}$	gate-drain charge		-	0.3	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	122	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	11	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	9	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -15 V; $I_{D}$ = -1 A; $V_{GS}$ = -4.5 V;	-	3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega$ ; $T_j = 25 °C$	-	6	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	22	-	ns
t <sub>f</sub>	fall time		-	5	-	ns
Source-drai	in diode		I	1	1	1
$V_{SD}$	source-drain voltage	$I_S = -0.7 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-1	-1.2	V
						1

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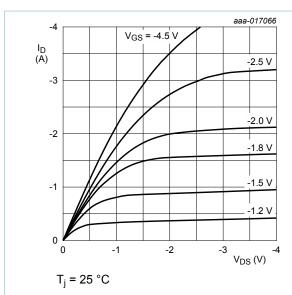
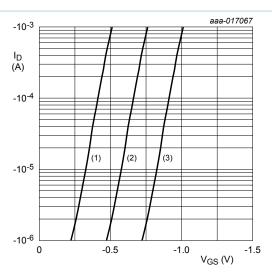


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values



 $V_{DS}$  = -5 V

T<sub>i</sub> = 25 °C

(1) minimum values

(2) typical values

(3) maximum values

Fig. 8. Sub-threshold drain current as a function of gate-source voltage

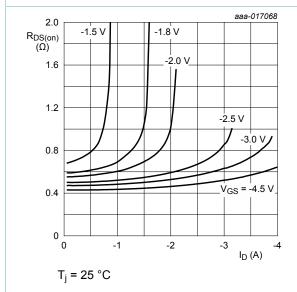


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

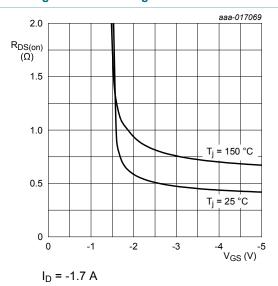


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

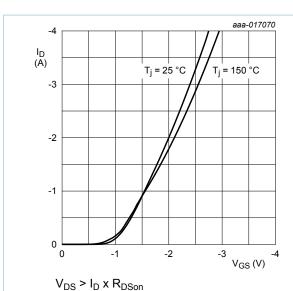


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

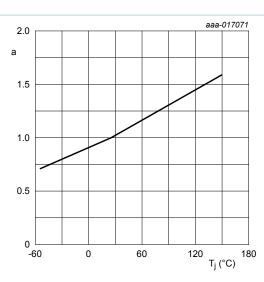
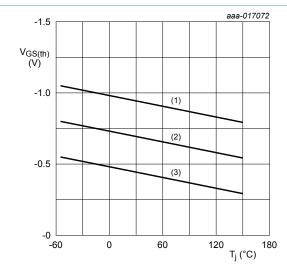


Fig. 12. Normalized drain-source on-state resistance as a function of ambient temperature; typical values

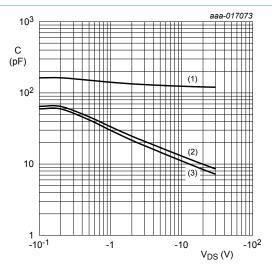
$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$



 $I_D = -250 \mu A; V_{DS} = V_{GS}$ 

- (1) maximum values
- (2) typical values
- (3) maximum values

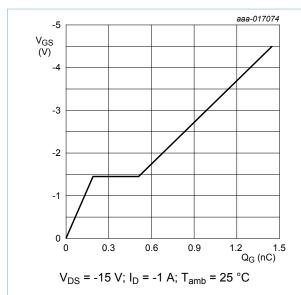
Fig. 13. Gate-source threshold voltage as a function of ambient temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

- (1) C<sub>iss</sub>
- (2) C<sub>oss</sub>
- (3)  $C_{rss}$

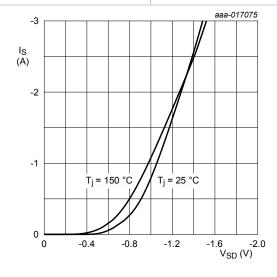
Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



V<sub>GS</sub>(pl)
V<sub>GS</sub>(th)
V<sub>GS</sub>(th)
V<sub>GS</sub>(th)
V<sub>GS</sub>(th)
003aaa508

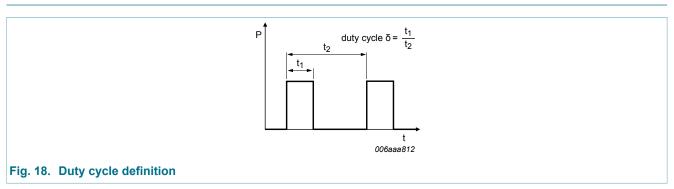
Fig. 16. Gate charge waveform definitions

Fig. 15. Gate-source voltage as a function of gate charge; typical values



 $V_{GS}$  = 0 V Fig. 17. Source current as a function of source-drain voltage; typical values

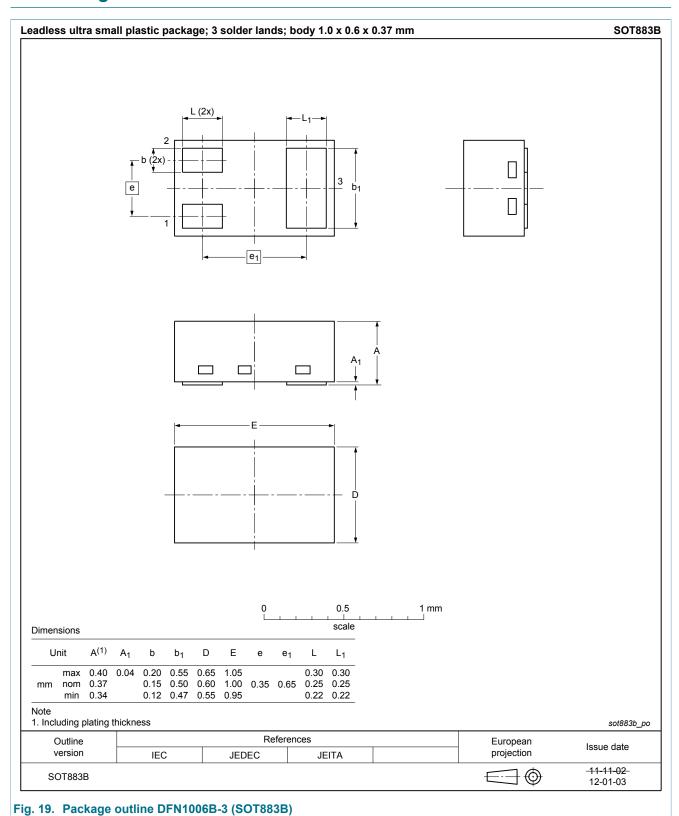
## 11. Test information



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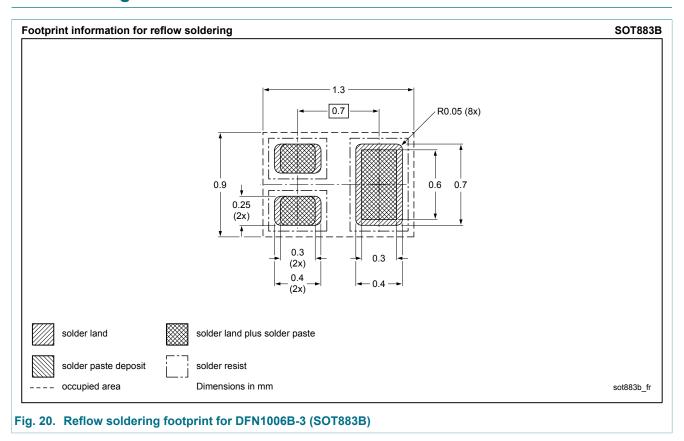
## 12. Package outline



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## 13. Soldering



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30 V, P-channel Trench MOSFET

# 14. Revision history

#### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMZB320UPE v.1	20150324	Product data sheet	-	-

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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